

PowerPoint® Lectures for
University Physics, 14th Edition, Global Edition
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Chapter 25

Current, Resistance, and Electromotive Force

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Goals for Chapter 25

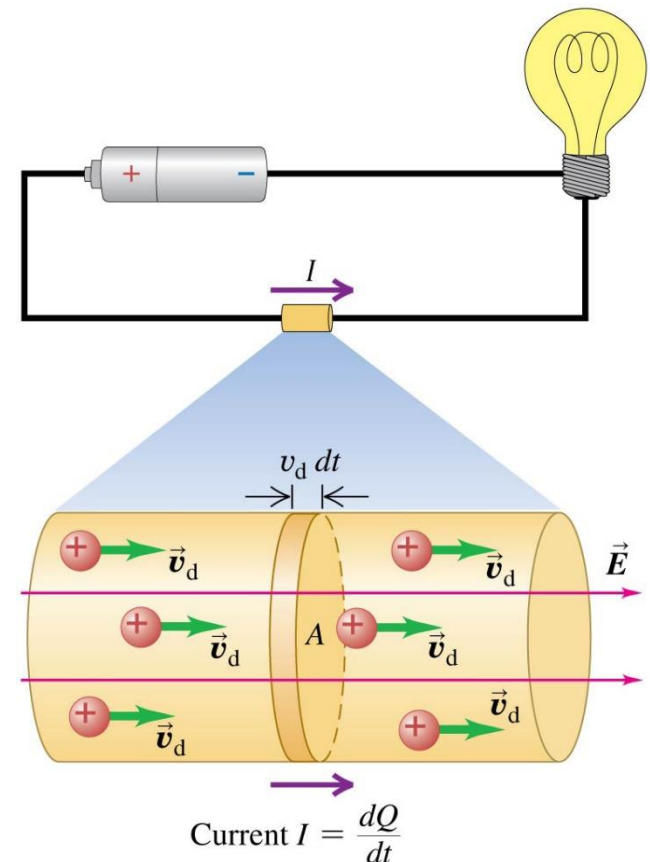
- **Electric current**
- **Resistivity and conductivity**
- **Resistance**
- **Electromotive force**
- **Energy and power in electric circuits**

25.1 Current

- A **current** is any motion of charge from one region to another.

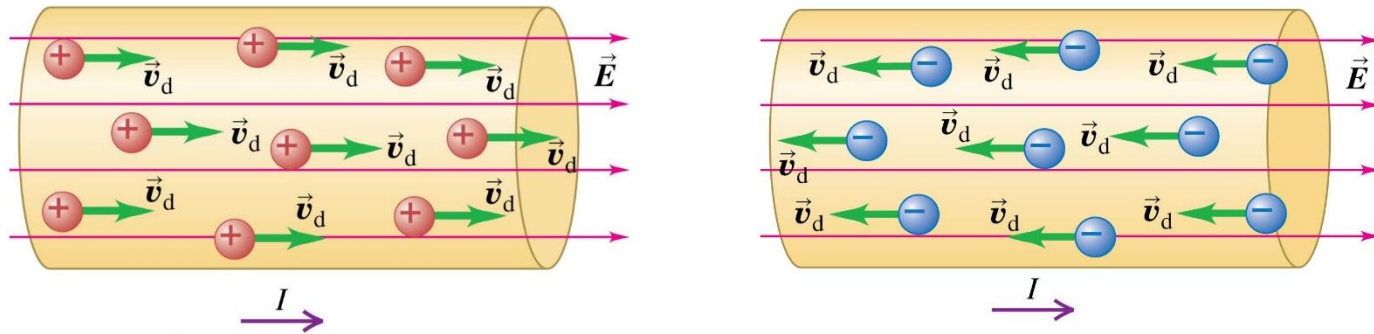
$$I = \frac{dQ}{dt}$$

- SI unit of current: **ampere, A** = C/s



Direction of current flow

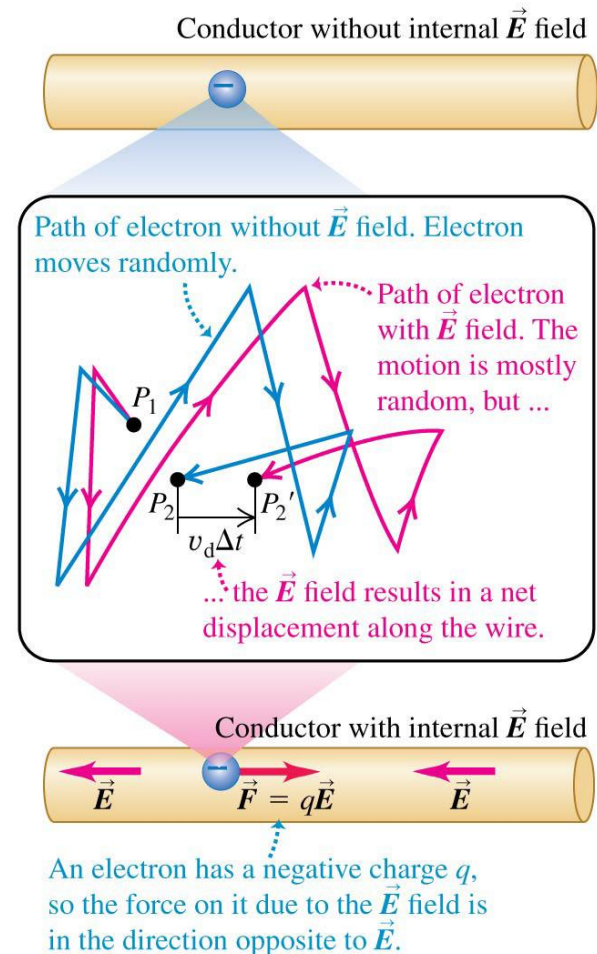
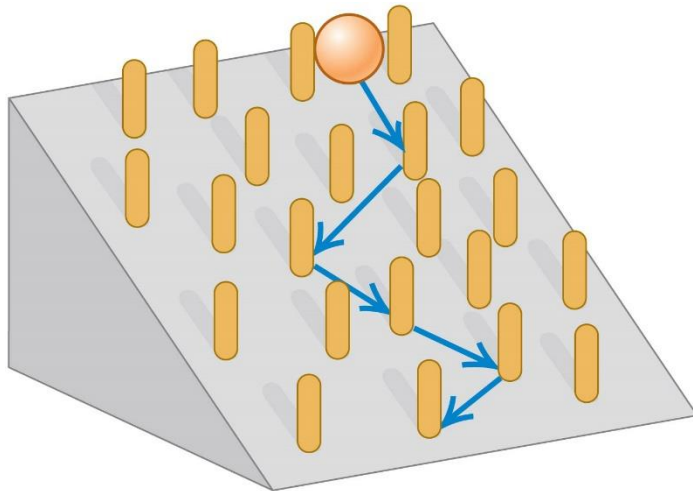
- A current can be produced by **positive or negative charge flow**.



- Conventional **current** is treated as a **flow of positive charges**.
- In a metallic conductor, the moving charges are electrons — but the current still points in the direction positive charges would flow.

25.6 Metallic conduction*

- **Electrons in a conductor** are free to move, colliding at intervals with the stationary positive ions.
- The motion of the electrons is analogous to the motion of a ball rolling down a pinball machine.



\vec{v}_d : drift velocity

$$v_d \propto E$$

Drift velocity and current density

- We can define a **vector current density** that includes the direction of the **drift velocity**:

$$\vec{J} = nq\vec{v}_d$$

Diagram illustrating the components of the vector current density equation $\vec{J} = nq\vec{v}_d$:

- Vector current density** points to \vec{J} .
- Concentration of moving charged particles** points to n .
- Charge per particle** points to q .
- Drift velocity** points to \vec{v}_d .

- The vector current density is always in the same direction as the electric field, no matter what the signs of the charge carriers are.

$$I = \int \vec{J} \cdot d\vec{A} = nqv_d A$$

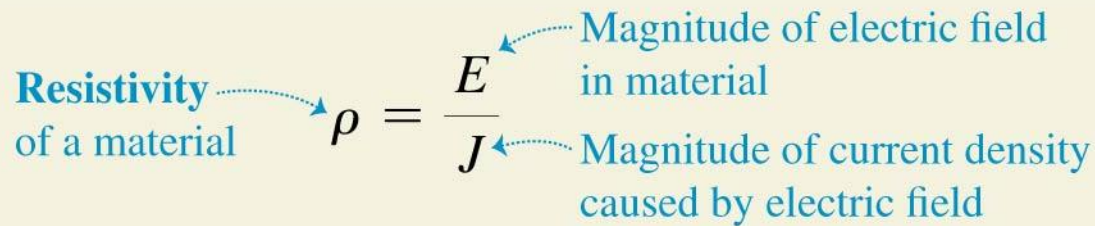
$$I = \frac{dQ}{dt} = n|q|v_d A$$

Diagram illustrating the components of the current equation $I = \frac{dQ}{dt} = n|q|v_d A$:

- Current through an area** points to I .
- Rate at which charge flows through area** points to $\frac{dQ}{dt}$.
- Concentration of moving charged particles** points to n .
- Charge per particle** points to $|q|$.
- Drift speed** points to v_d .
- Cross-sectional area** points to A .

25.2 Resistivity

- The **resistivity** ρ of a material is the ratio of the electric field in the material to the current density it causes:
- The **conductivity** σ is the reciprocal of the resistivity.



The diagram shows the formula $\rho = \frac{E}{J}$ on a light yellow background. A blue dotted arrow points from the word "Resistivity" to the symbol ρ , with the text "of a material" below it. Another blue dotted arrow points from the text "Magnitude of electric field in material" to the symbol E in the numerator. A third blue dotted arrow points from the text "Magnitude of current density caused by electric field" to the symbol J in the denominator.

$$\text{Resistivity of a material } \rho = \frac{E}{J}$$

Magnitude of electric field in material

Magnitude of current density caused by electric field

$$\vec{J} = \rho^{-1} \vec{E}$$

$$\vec{J} = \sigma \vec{E}$$

Resistivities at room temperature (20°C)

TABLE 25.1 Resistivities at Room Temperature (20°C)

Substance			ρ ($\Omega \cdot \text{m}$)	Substance			ρ ($\Omega \cdot \text{m}$)
Conductors				Semiconductors			
Metals	Silver		1.47×10^{-8}		Pure carbon (graphite)		3.5×10^{-5}
	Copper		1.72×10^{-8}		Pure germanium		0.60
	Gold		2.44×10^{-8}		Pure silicon		2300
	Aluminum		2.75×10^{-8}	Insulators			
	Tungsten		5.25×10^{-8}				
	Steel		20×10^{-8}				
	Lead		22×10^{-8}				
		Mercury		95×10^{-8}		Amber	
Alloys	Manganin (Cu 84%, Mn 12%, Ni 4%)		44×10^{-8}		Glass		$10^{10}\text{--}10^{14}$
	Constantan (Cu 60%, Ni 40%)		49×10^{-8}		Lucite		$>10^{13}$
	Nichrome		100×10^{-8}		Mica		$10^{11}\text{--}10^{15}$
					Quartz (fused)		75×10^{16}
				Sulfur		10^{15}	
				Teflon		$>10^{13}$	
				Wood		$10^8\text{--}10^{11}$	

Resistivity and temperature*

- The resistivity of a metallic conductor nearly always increases with increasing temperature.

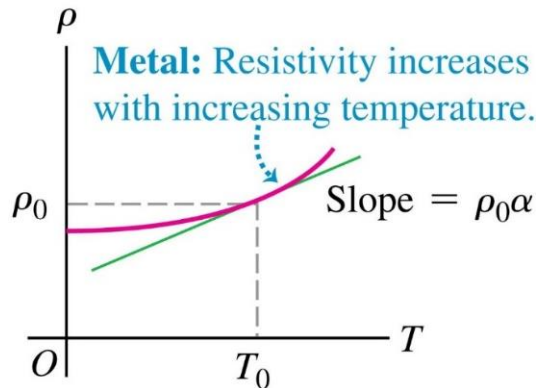
Temperature dependence of resistivity:

Resistivity at temperature T

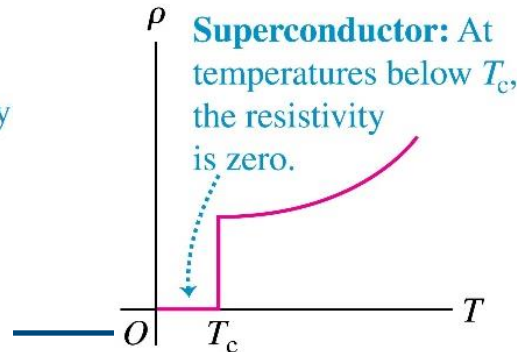
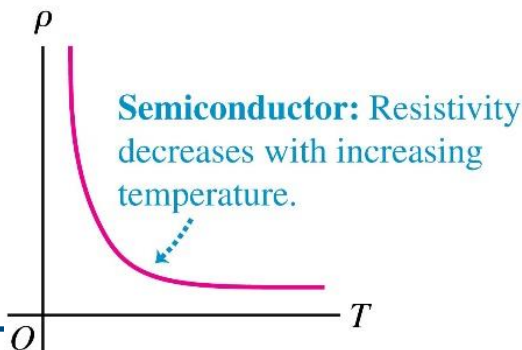
$$\rho(T) = \rho_0[1 + \alpha(T - T_0)]$$

Resistivity at reference temperature T_0

Temperature coefficient of resistivity



Material	α [$(^\circ\text{C})^{-1}$]
Aluminum	0.00039
Carbon (graphite)	-0.0005
Copper	0.00393
Iron	0.0050
Lead	0.0043
Silver	0.0038
Tungsten	0.0045

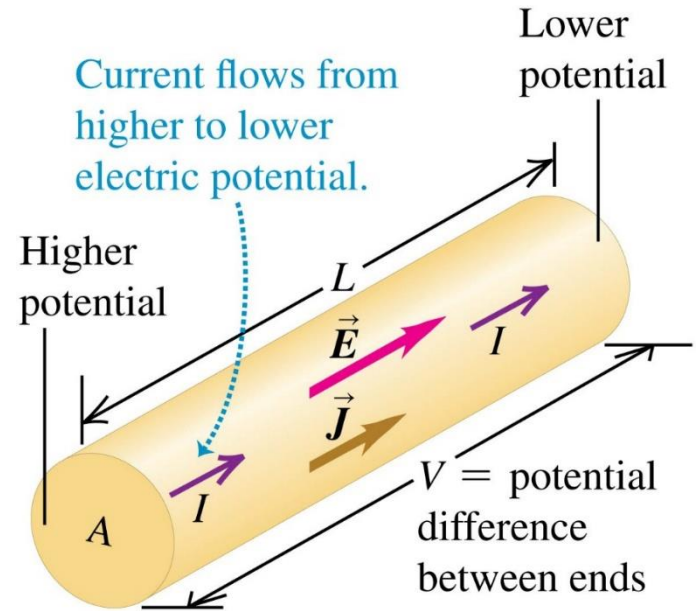


25.3 Resistance

- **Ohm's law:**

voltage drop (V) \propto current (I)

$$V = RI \rightarrow R \equiv \frac{V}{I}$$



- **Resistance R** of a (cylindrical) conductor:

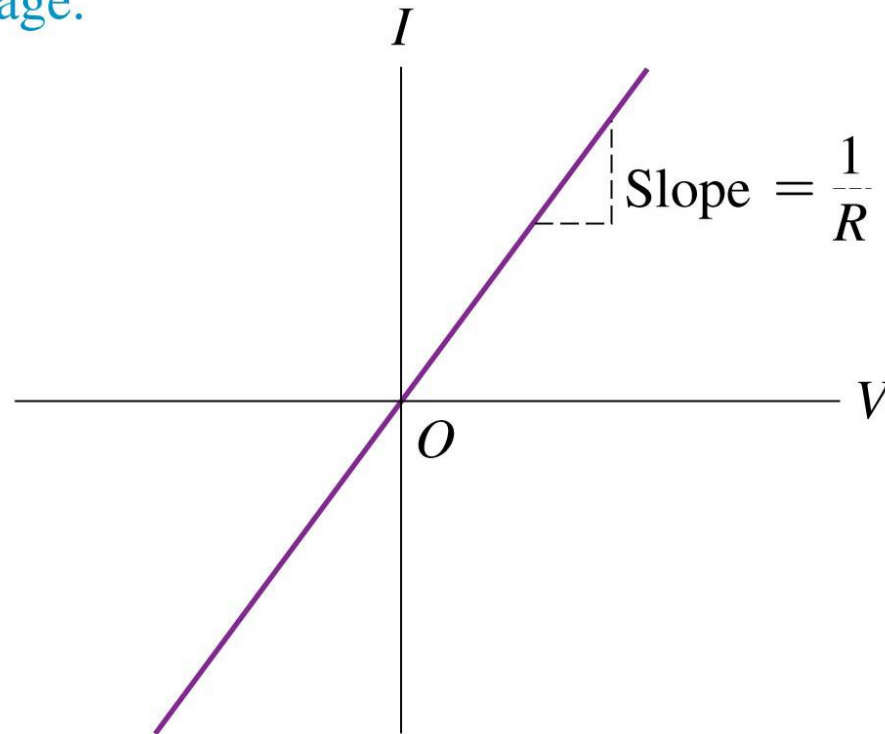
$$R = \frac{V}{I} = \frac{EL}{JA} = \rho \frac{L}{A} \quad (\because E = \rho J)$$

- SI unit of resistance: **ohm, Ω**

Ohmic resistors

- Resistors that obey the Ohm's law.
- Current vs. potential difference (voltage) is linear. $I = V/R$

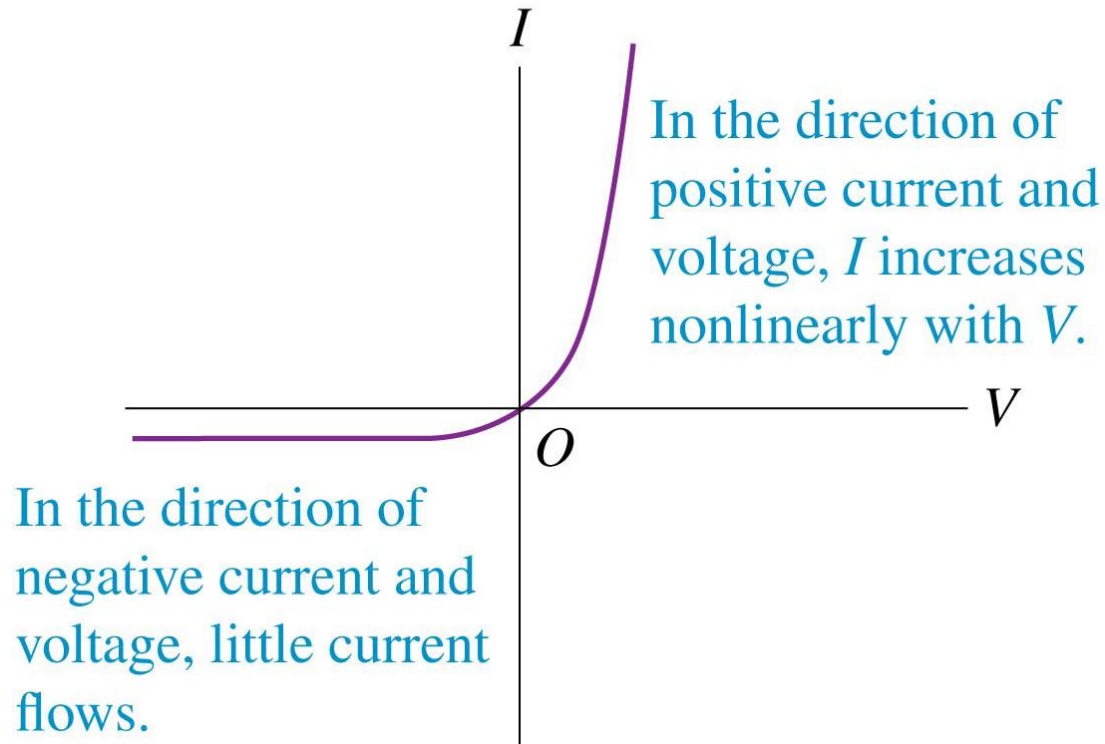
Ohmic resistor (e.g., typical metal wire): At a given temperature, current is proportional to voltage.



Non-Ohmic resistors*

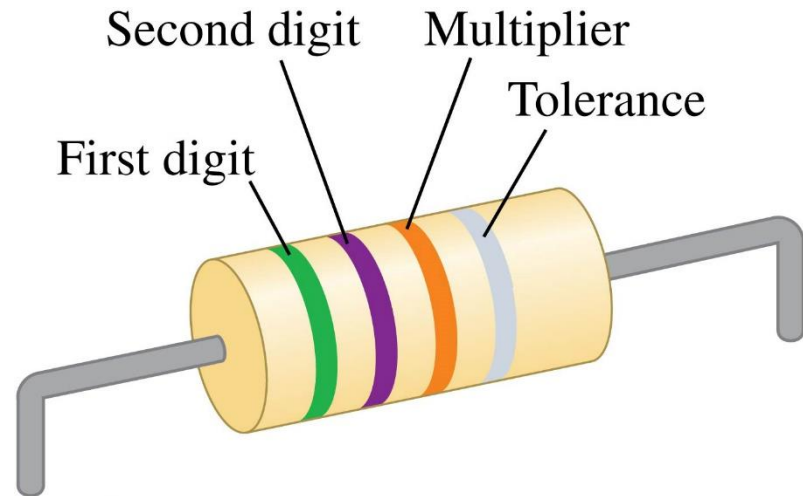
- Example: semiconductor **diode**

Semiconductor diode: a nonohmic resistor



Color-code for resistors*

Color	Value as Digit	Value as Multiplier
Black	0	1
Brown	1	10
Red	2	10 ²
Orange	3	10 ³
Yellow	4	10 ⁴
Green	5	10 ⁵
Blue	6	10 ⁶
Violet	7	10 ⁷
Gray	8	10 ⁸
White	9	10 ⁹



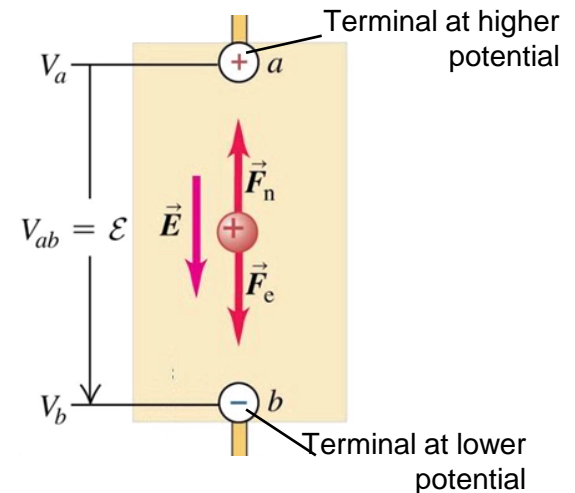
- 5.7 k Ω with a tolerance of $\pm 10\%$.

25.4 Electromotive force and circuits

- **Electromotive force (emf, \mathcal{E})** is the influence (“pump”) which makes current flow from lower to higher potential. A circuit element that provides emf is called a **source of emf**.
- “emf” is **not a force but similar to potential**.
- SI unit of emf: V (= J/C). “Volt”
- For ideal source of emf (or in open-circuit condition),

$$\begin{aligned}\mathcal{E} &= \frac{\text{Work done on } q \text{ by } F_n}{q} \\ &= \frac{qV_{ab}}{q} = V_{ab}\end{aligned}$$

V_{ab} : terminal voltage (difference)



F_n : Nonelectrostatic force *moving* charge to higher potential

F_e : Force due to electric field

For open circuit (no net motion of charge), $F_n = F_e$.

Internal resistance

- Real sources of emf contain some **internal resistance r** . When the circuit is closed and a current (I) flows, a voltage drop (rI) corresponding to the resistive loss of energy occurs within the emf source.

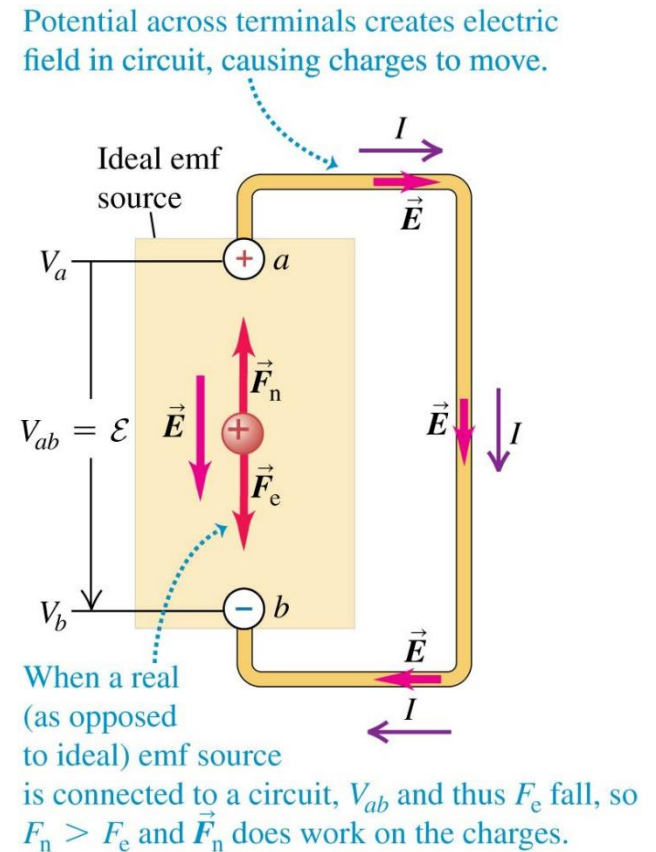
(Work done on q by F_n) = qV_{ab} + (Resistive energy loss)

$$\mathcal{E} = V_{ab} + rI$$

Note that the **terminal voltage** becomes less than the emf (= open-circuit terminal voltage).

- The current through the source:

$$V_{ab} = \mathcal{E} - rI = IR \quad \rightarrow \quad I = \frac{\mathcal{E}}{R + r}$$





Alessandro Volta (☼1745, †1827)

Inventor of battery

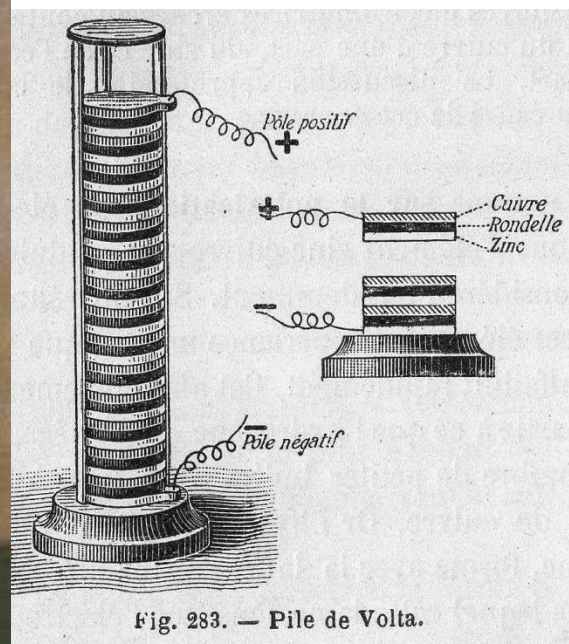
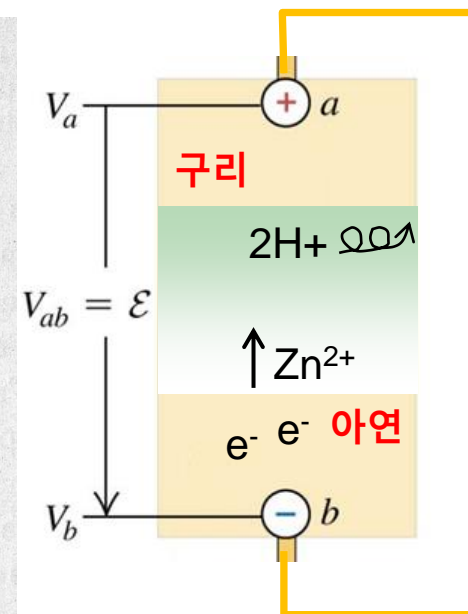


Fig. 283. — Pile de Volta.



The nonelectrostatic force F_n comes from chemical (redox) reactions:

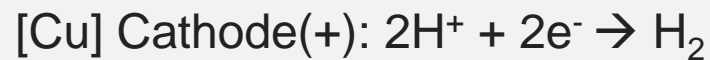
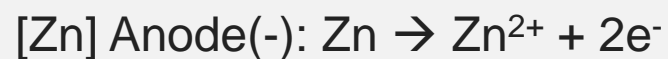


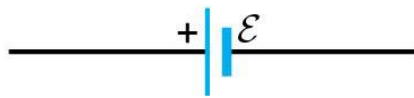
Table 25.4 — Symbols for circuit diagrams



Conductor with negligible resistance



Resistor

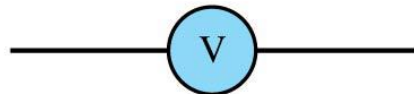
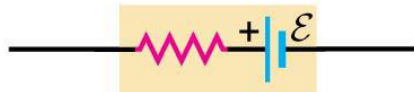


Source of emf (longer vertical line always represents the positive terminal, usually the terminal with higher potential)

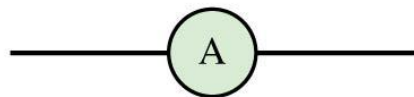


Source of emf with internal resistance r (r can be placed on either side)

or



Voltmeter (measures potential difference between its terminals)



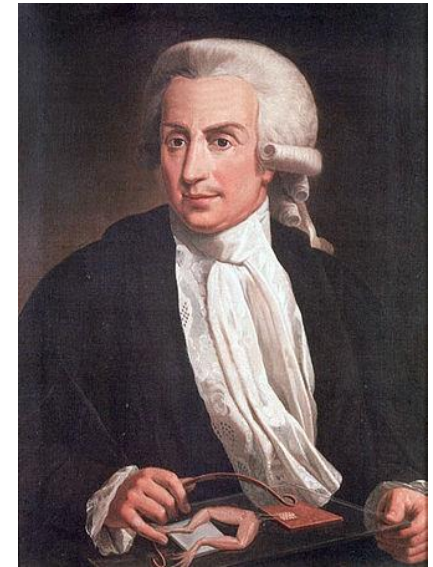
Ammeter (measures current through it)



André-Marie Ampère (☼1775, †1836)
electromagnetism

*Listen to learned men, but do so only
with one ear.*

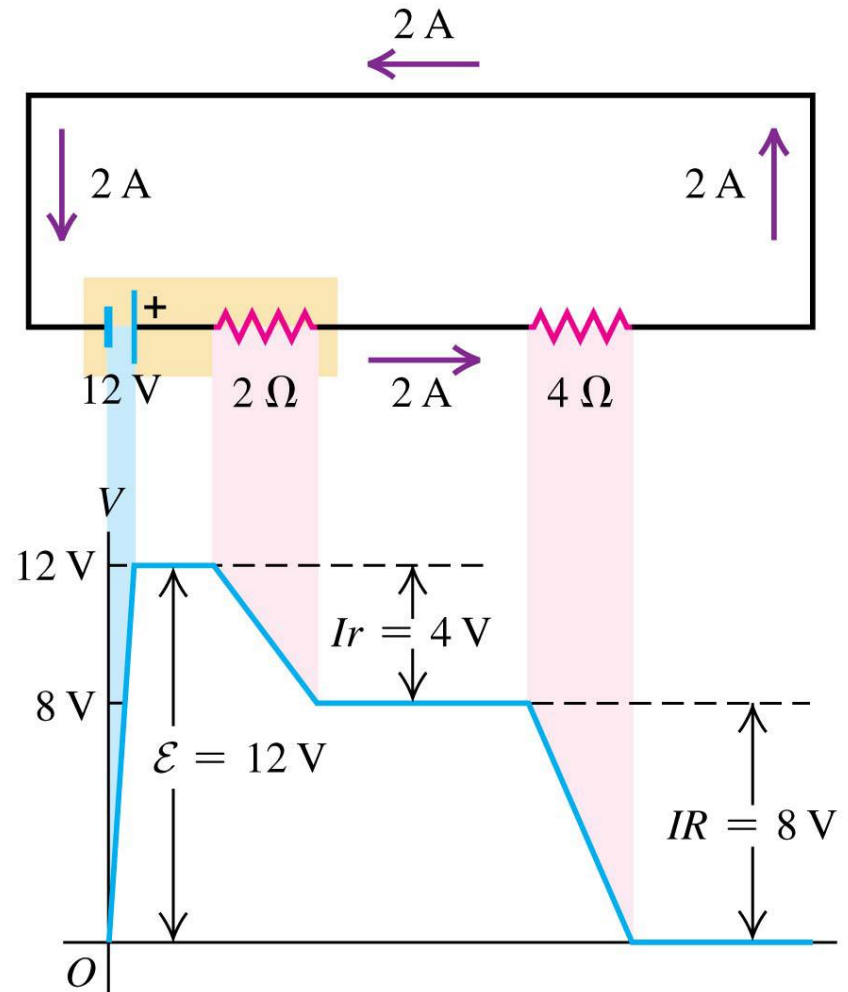
*Let the other be always ready to
receive the sweet accents of the voice
of your heavenly Friend.*



Luigi Galvani (☼1737, †1798)
Bioelectricity

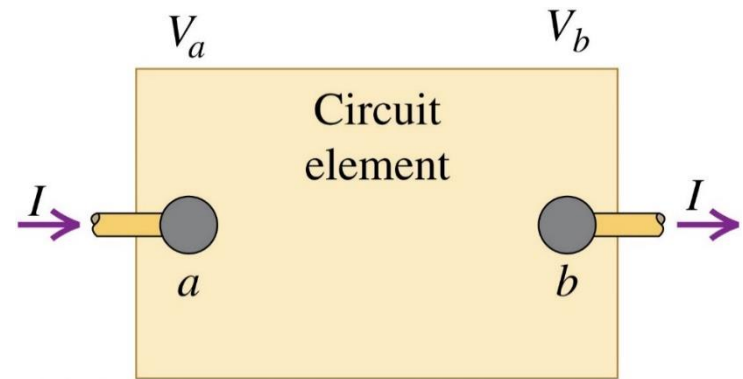
Potential changes around a circuit

- The potential **rises** when the current goes through a **battery**, and **drops** when it goes through a **resistor**.
- Going all the way around the loop brings the potential back to where it started.



25.5 Energy and power in electric circuits

- A circuit element with potential difference $V_{ab} = V_a - V_b$ between its terminals and current I passing through it in the direction from a toward b .
- The time rate of energy transfer is **power** P :



Power delivered to
or extracted from
a circuit element

$$P = V_{ab}I$$

Voltage across
circuit element

Current in circuit element

$$W = V_{ab}Q \rightarrow \frac{dW}{dt} = V_{ab} \frac{dQ}{dt}$$

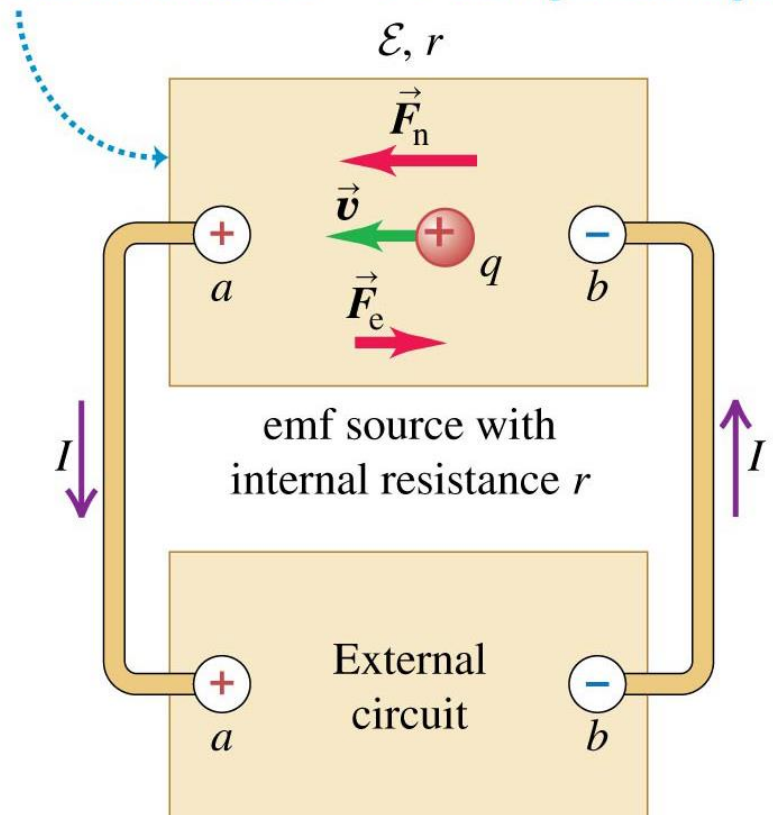
$$P \equiv \frac{dW}{dt} = V_{ab}I = \frac{V_{ab}^2}{R} = I^2 R$$

in case of resistive circuit

Power output of an emf source

- A source with emf \mathcal{E} and internal resistance r connected by ideal wires to an external circuit
- $V_a > V_b \rightarrow V_{ab} > 0$
- Power generated by the emf source: $P_{\text{emf}} = \mathcal{E}I$
- Power delivered to the external circuit: $P = V_{ab}I$
- Power dissipated in the internal resistance: $P_r = I^2r = P_{\text{emf}} - P$

- The emf source converts nonelectrical to electrical energy at a rate $\mathcal{E}I$.
- Its internal resistance *dissipates* energy at a rate I^2r .
- The difference $\mathcal{E}I - I^2r$ is its power output.



$$P = \mathcal{E}I - I^2r$$

25 Summary

- **Current and current density**
 - **Resistivity and resistors**
 - **Circuits and emf**
 - **Energy and power in electric circuits**
-